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# HD74HCT640/HD74HCT643

Octal Bus Transceivers (with 3-state outputs)

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## Description

Both the HD74HCT640 and the HD74HCT643 have one active low enable input ( $\overline{G}$ ), and a direction control (DIR). When the DIR input is high, data flows from the A inputs to the B outputs. When DIR is low, data flows from B to A.

The HD74HCT640 transfers inverted data from one bus to the other. The HD74HCT643 transfers inverted data from the A bus to the B bus and non-inverted data from the B bus to the A bus.

## Features

- LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility
- High Speed Operation:  $t_{pd}$  (A to B) = 14.5 ns typ ( $C_L = 50$  pF)
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 4.5$  to 5.5 V
- Low Input Current: 1  $\mu$ A max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max ( $T_a = 25^\circ\text{C}$ )

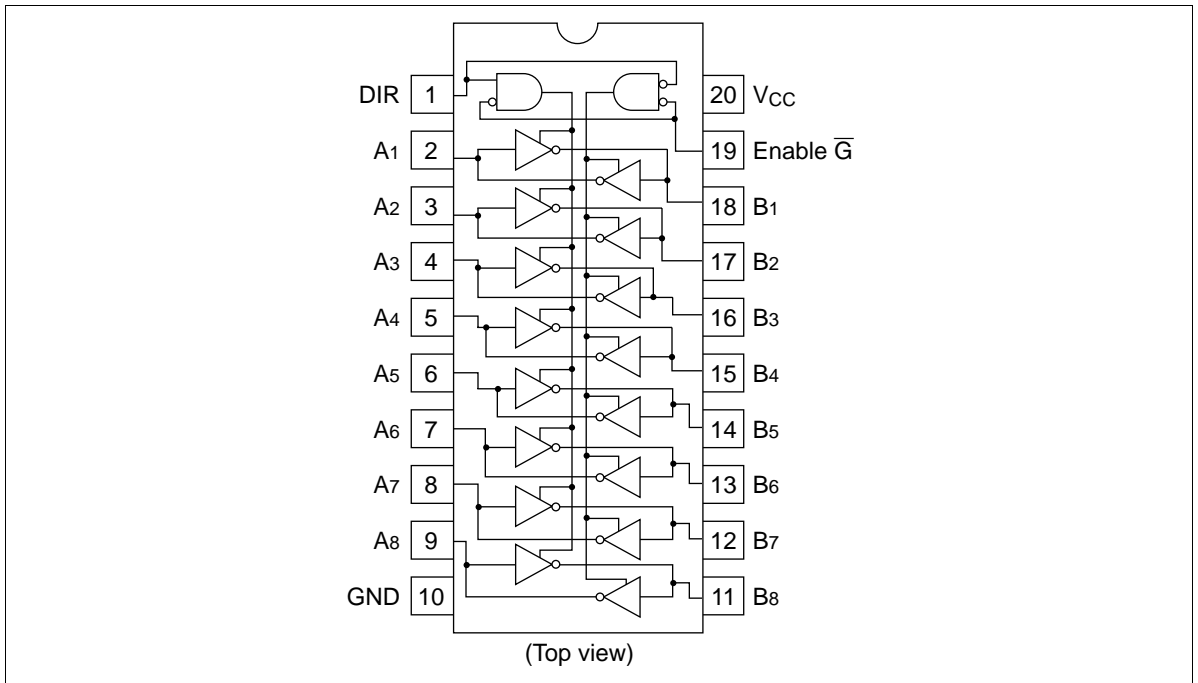
## Function Table

Control Input		Operation	
$\overline{G}$	DIR	HD74HCT640	HD74HCT643
L	L	$\overline{B}$ data to A bus	B data to A bus
L	H	$\overline{A}$ data to B bus	$\overline{A}$ data to B bus
H	X	Isolation	Isolation

# HD74HCT640/HD74HCT643

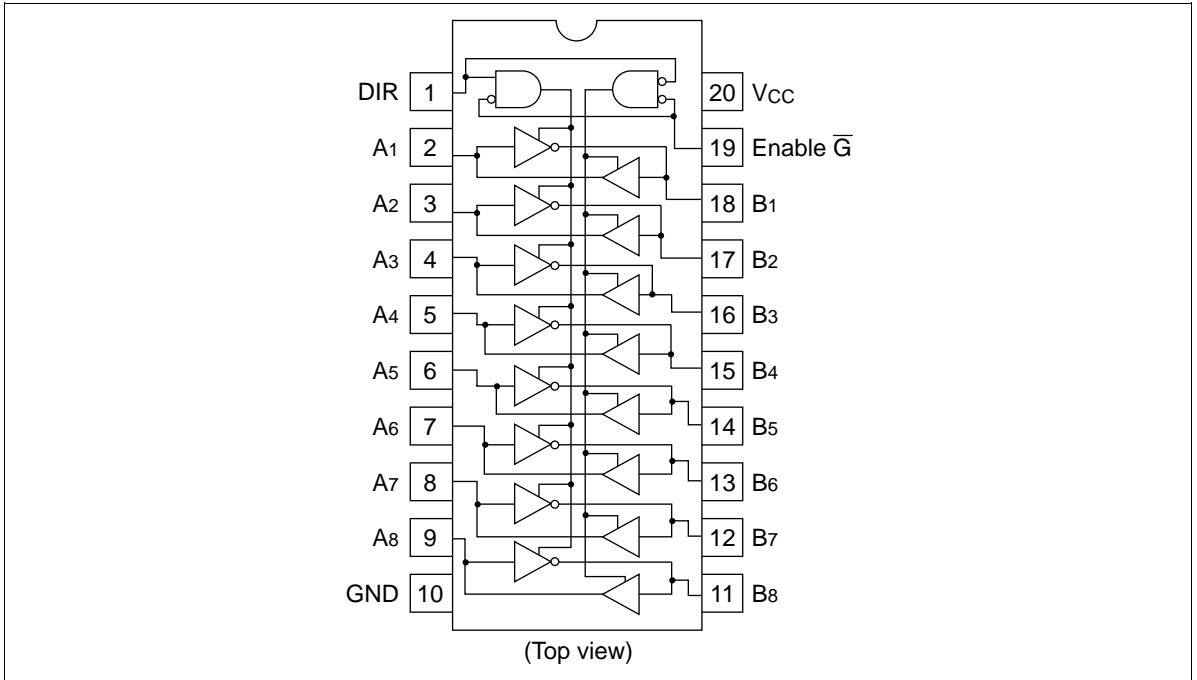
## Pin Arrangement

### HD74HCT640



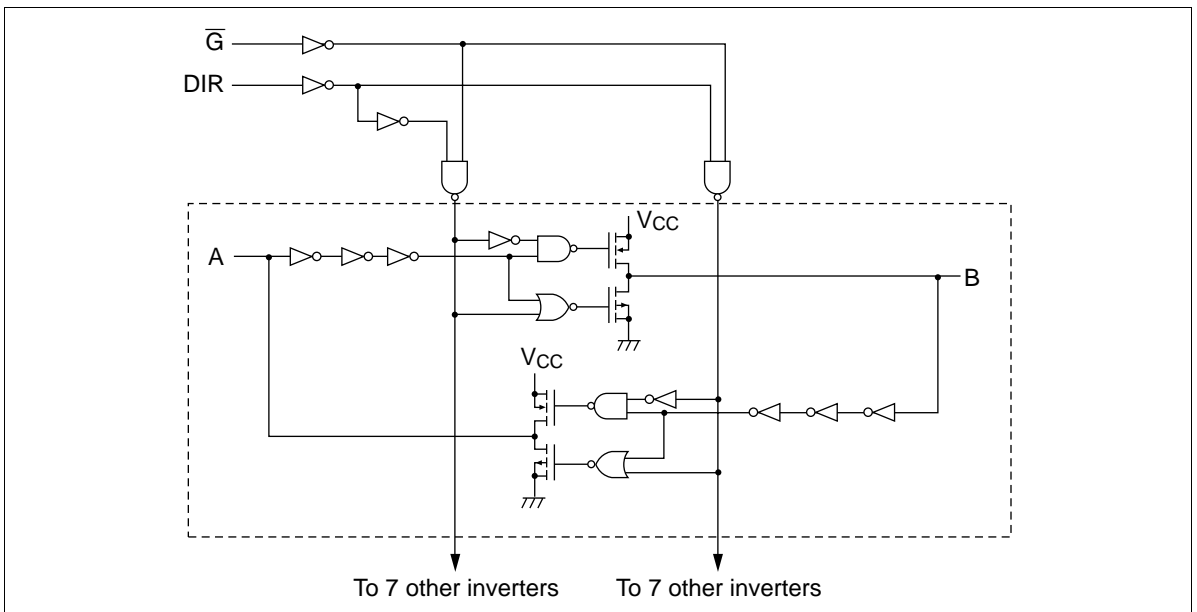
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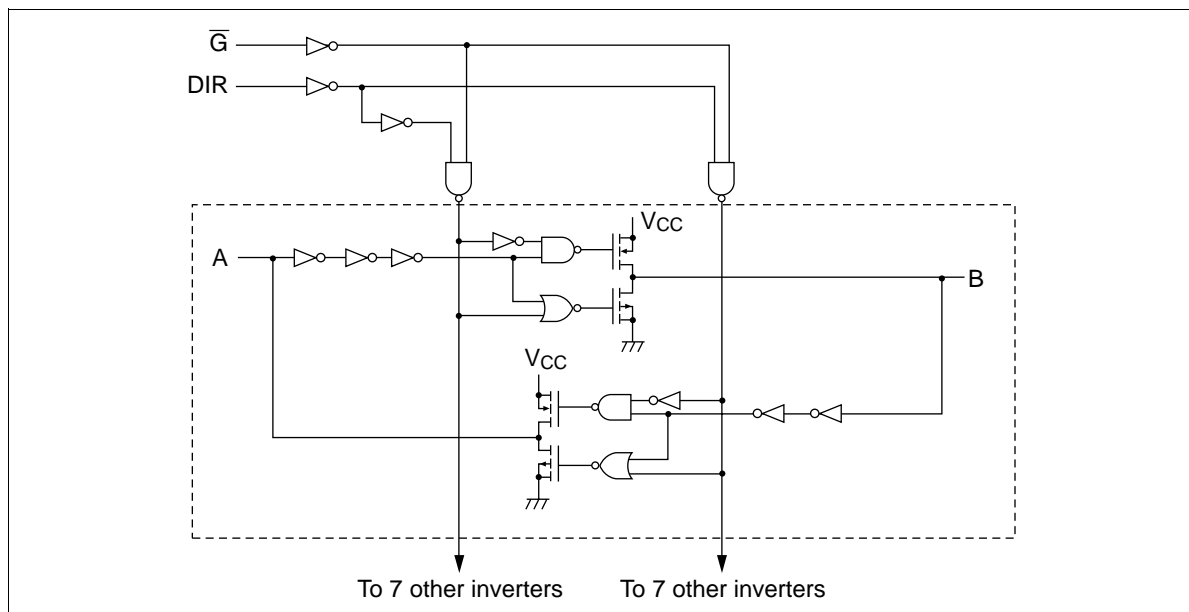
Block Diagram

HD74HCT640



# HD74HCT640/HD74HCT643

## HD74HCT643



### Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to +7.0	V
Input voltage	$V_{IN}$	-0.5 to $V_{CC} + 0.5$	V
Output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
DC current drain per pin	$I_{OUT}$	$\pm 35$	mA
DC current drain per $V_{CC}$ , GND	$I_{CC}$ , $I_{GND}$	$\pm 75$	mA
DC input diode current	$I_{IK}$	$\pm 20$	mA
DC output diode current	$I_{OK}$	$\pm 20$	mA
Power dissipation per package	$P_T$	500	mW
Storage temperature	Tstg	-65 to +150	$^{\circ}C$

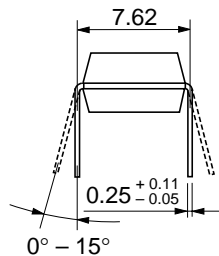
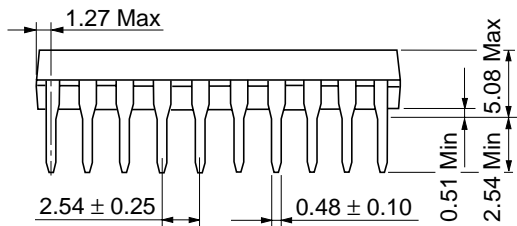
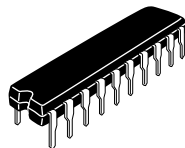
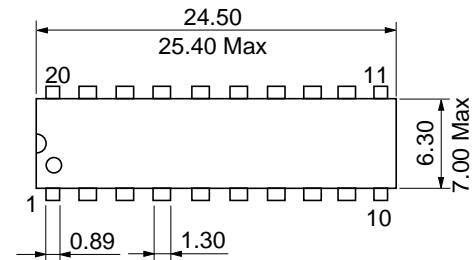
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**DC Characteristics**

Item	Symbol	Ta = 25°C		Ta = -40 to +85°C		Unit	Test Conditions	
		Min	Typ	Max	Min		Max	V <sub>CC</sub> (V)
Input voltage	V <sub>IH</sub>	2.0	—	—	2.0	—	V	4.5 to 5.5
	V <sub>IL</sub>	—	—	0.8	—	0.8	V	4.5 to 5.5
Output voltage	V <sub>OH</sub>	4.4	—	—	4.4	—	V	4.5 Vin = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> = -20 μA
		4.18	—	—	4.13	—		4.5 I <sub>OH</sub> = -6 mA
	V <sub>OL</sub>	—	—	0.1	—	0.1	V	4.5 Vin = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> = 20 μA
		—	—	0.26	—	0.33		4.5 I <sub>OL</sub> = 6 mA
Off-state output current	I <sub>OZ</sub>	—	—	±0.5	—	±5.0	μA	5.5 Vin = V <sub>IH</sub> or V <sub>IL</sub> , Vout = V <sub>CC</sub> or GND
Input current	I <sub>in</sub>	—	—	±0.1	—	±1.0	μA	5.5 Vin = V <sub>CC</sub> or GND
Quiescent current	I <sub>CC</sub>	—	—	4.0	—	40	μA	5.5 Vin = V <sub>CC</sub> or GND, Iout = 0 μA

**AC Characteristics (C<sub>L</sub> = 50 pF, Input t<sub>r</sub> = t<sub>f</sub> = 6 ns)**

Item	Symbol	Ta = 25°C		Ta = -40 to +85°C		Unit	Test Conditions	
		Min	Typ	Max	Min		Max	V <sub>CC</sub> (V)
Propagation delay time	t <sub>PLH</sub>	—	13	18	—	23	ns	4.5
	t <sub>PHL</sub>	—	16	18	—	23		4.5
Output enable time	t <sub>ZH</sub>	—	16	46	—	58	ns	4.5
	t <sub>ZL</sub>	—	16	46	—	58		4.5
Output disable time	t <sub>HZ</sub>	—	17	43	—	54	ns	4.5
	t <sub>LZ</sub>	—	21	43	—	54		4.5
Output rise/fall time	t <sub>TLH</sub> t <sub>THL</sub>	—	4	12	—	15	ns	4.5
Input capacitance	C <sub>in</sub>	—	5	10	—	10	pF	—



Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Weight (reference value)	1.26 g

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